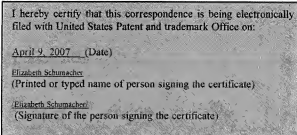


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Wen Lin, et al.  
Serial No.: 10/814,682  
Filed: March 31, 2004  
Title: **SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE  
MATCHING LAYER AND A METHOD OF MANUFACTURE  
THEREFOR**  
Grp./A.U.: 2823  
Examiner: Julio J. Maldonado Confirmation No. 8308

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450



Sir:

**AMENDMENT UNDER 37 C.F.R. § 1.111**

In response to the Examiner's Action mailed December 7, 2006, please amend the above-identified application as follows: